

TOSHIBA Power Transistor Module Silicon NPN Epitaxial Type (Darlington power transistor 4 in 1)

## MP4104

High Power Switching Applications.

Hammer Drive, Pulse Motor Drive and Inductive Load Switching.

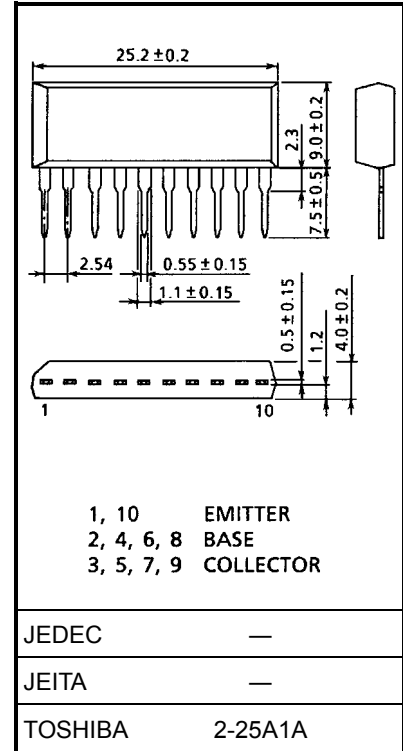
- Small package by full molding (SIP 10 pin)
- High collector power dissipation (4 devices operation)  
:  $P_T = 4 \text{ W}$  ( $T_a = 25^\circ\text{C}$ )
- High collector current:  $I_C$  (DC) = 4 A (max)
- High DC current gain:  $h_{FE} = 2000$  (min) ( $V_{CE} = 2 \text{ V}$ ,  $I_C = 1.5 \text{ A}$ )

### Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics		Symbol	Rating	Unit
Collector-base voltage		$V_{CBO}$	120	V
Collector-emitter voltage		$V_{CEO}$	100	V
Emitter-base voltage		$V_{EBO}$	6	V
Collector current	DC	$I_C$	4	A
	Pulse	$I_{CP}$	6	
Continuous base current		$I_B$	0.5	A
Collector power dissipation (1 device operation)		$P_C$	2.0	W
Collector power dissipation (4 devices operation)		$P_T$	4.0	W
Junction temperature		$T_j$	150	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	-55 to 150	$^\circ\text{C}$

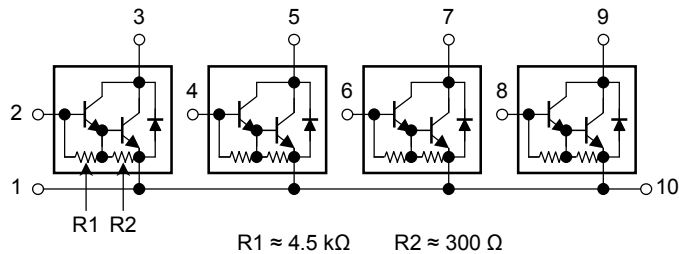
Industrial Applications

Unit: mm



Weight: 2.1 g (typ.)

### Array Configuration

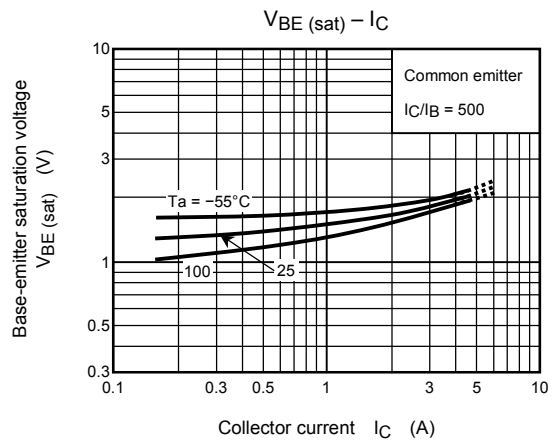
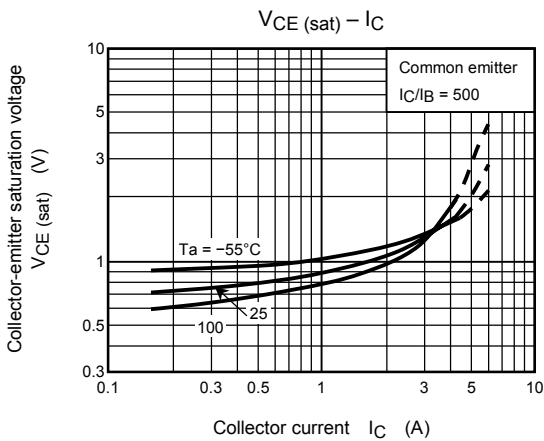
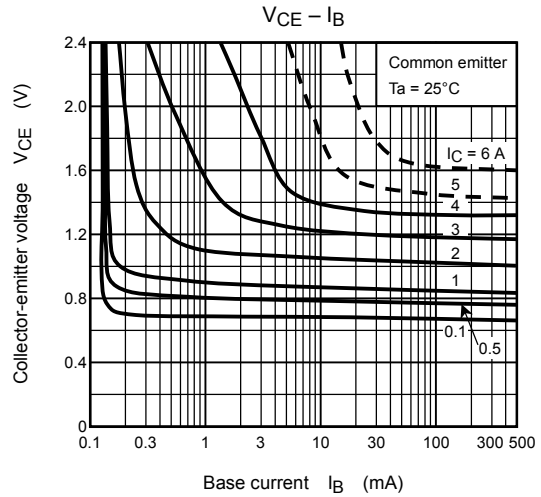
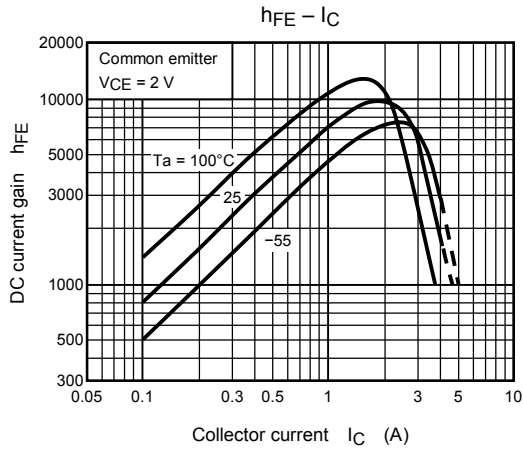
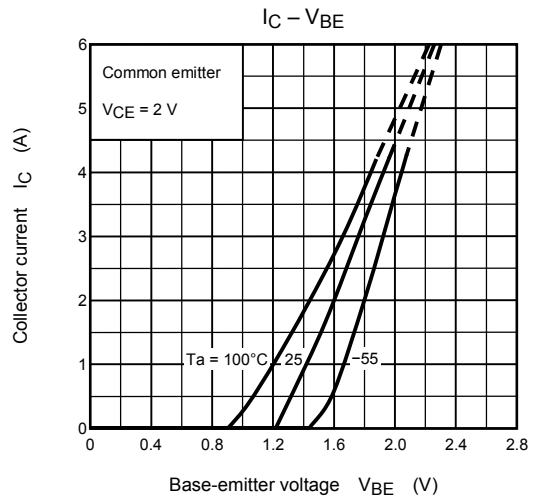
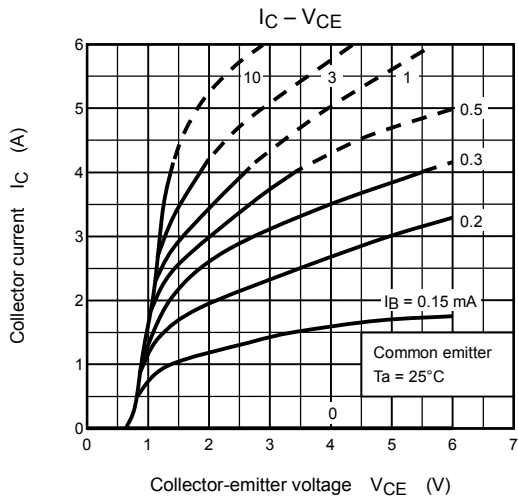


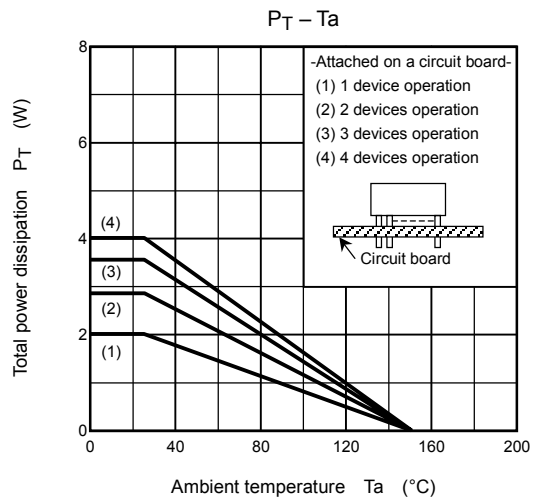
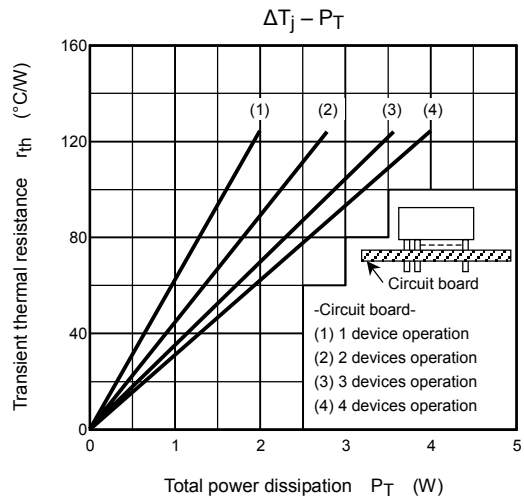
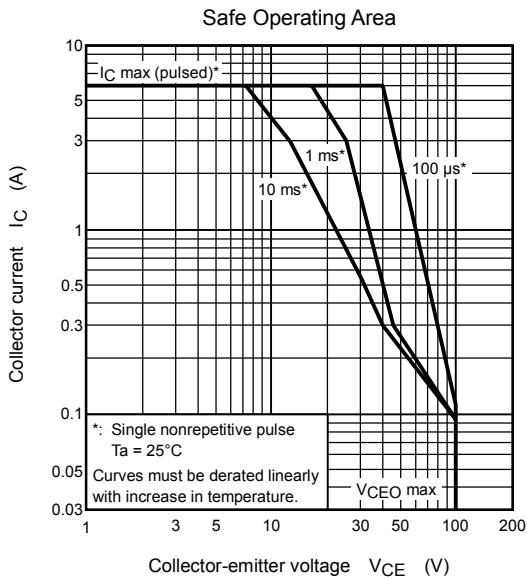
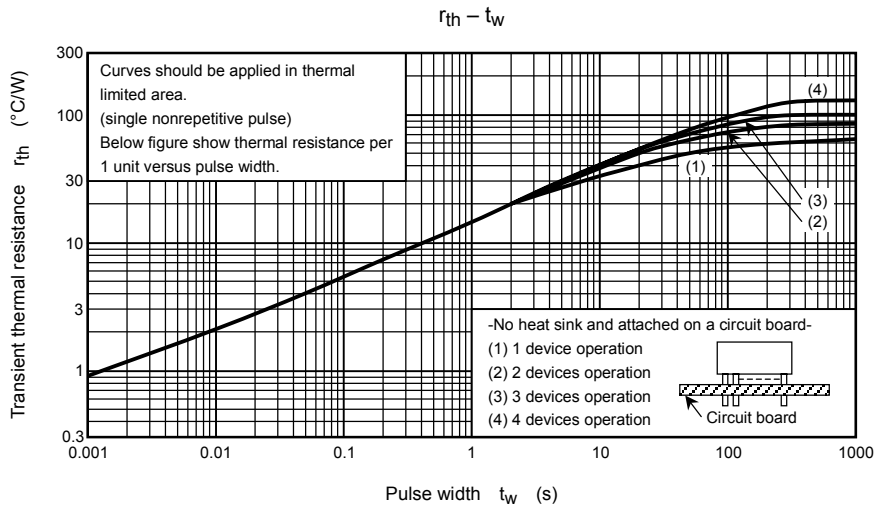
## Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance of junction to ambient (4 devices operation, $T_a = 25^\circ\text{C}$ )	$\Sigma R_{th(j-a)}$	31.3	$^\circ\text{C/W}$
Maximum lead temperature for soldering purposes (3.2 mm from case for 10 s)	$T_L$	260	$^\circ\text{C}$

## Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		$I_{CBO}$	$V_{CB} = 120\text{ V}, I_E = 0\text{ A}$	—	—	10	$\mu\text{A}$
Collector cut-off current		$I_{CEO}$	$V_{CE} = 100\text{ V}, I_B = 0\text{ A}$	—	—	10	$\mu\text{A}$
Emitter cut-off current		$I_{EBO}$	$V_{EB} = 6\text{ V}, I_C = 0\text{ A}$	0.5	—	2.5	mA
Collector-base breakdown voltage		$V_{(BR)CBO}$	$I_C = 1\text{ mA}, I_E = 0\text{ A}$	120	—	—	V
Collector-emitter breakdown voltage		$V_{(BR)CEO}$	$I_C = 10\text{ mA}, I_B = 0\text{ A}$	100	—	—	V
DC current gain		$h_{FE(1)}$	$V_{CE} = 2\text{ V}, I_C = 1.5\text{ A}$	2000	—	15000	—
		$h_{FE(2)}$	$V_{CE} = 2\text{ V}, I_C = 3.0\text{ A}$	1000	—	—	
Saturation voltage	Collector-emitter	$V_{CE(sat)}$	$I_C = 1.5\text{ A}, I_B = 3\text{ mA}$	—	—	1.5	V
	Base-emitter	$V_{BE(sat)}$	$I_C = 1.5\text{ A}, I_B = 3\text{ mA}$	—	—	2.0	
Transition frequency		$f_T$	$V_{CE} = 2\text{ V}, I_C = 0.5\text{ A}$	—	60	—	MHz
Collector output capacitance		$C_{ob}$	$V_{CB} = 10\text{ V}, I_E = 0\text{ A}, f = 1\text{ MHz}$	—	30	—	pF
Switching time	Turn-on time	$t_{on}$	<p style="text-align: center;"><math>I_{B1} = -I_{B2} = 3\text{ mA}</math></p>	—	0.3	—	$\mu\text{s}$
	Storage time	$t_{stg}$		—	2.0	—	
	Fall time	$t_f$		—	0.4	—	





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